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FEATURES

- 4096 bits of nonvolatile dual-port memory including real time clock/calendar in binary format, programmable interval timer, and programmable power-on cycle counter
- 1-Wire[®] interface for MicroLAN communication at 16.3kbits/s
- 3-wire host interface for high-speed data communications at 2Mb/s
- Unique, factory-lasered and tested 64-bit registration number (8-bit family code + 48-bit serial number + 8-bit CRC tester) assures absolute traceability because no two parts are alike
- Memory partitioned into 16 pages of 256-bits for packetizing data
- 256-bit scratchpad with strict read/write protocols ensures integrity of data transfer
- Programmable alarms can be set to generate interrupts for interval timer, real time clock, and/or cycle counter
- 16-pin DIP, SO, and SSOP packages
- Operating temperature range from -40°C to +85°C
- Operating voltage range from 2.8V to 5.5V

ORDERING INFORMATION

| DS2404-001 | 16-pin DIP |
|-----------------|-----------------------------|
| DS2404S-001 | 16-pin SO |
| DS2404B | 16-pin SSOP |
| DS2404S-001/T&R | Tape and Reel of S2404S-001 |
| DS2404B/T&R | Tape and Reel of DS2404B |

DESCRIPTION

The DS2404 EconoRAM Time Chip offers a simple solution for storing and retrieving vital data and time information with minimal hardware. The DS2404 contains a unique lasered ROM, real-time clock/calendar, interval timer, cycle counter, programmable interrupts, and 4096-bits of SRAM. Two separate ports are provided for communication: 1-Wire and 3-wire. Using the 1-Wire port, only one pin is required for communication, and the lasered-ROM can be read even when the DS2404 is without power. The 3-wire port provides high-speed communication using the traditional Dallas Semiconductor 3-wire interface. With either interface, a strict protocol for accessing the DS2404 ensures data integrity. Utilizing backup energy sources, the data is nonvolatile (NV) and allows for stand-alone operation.

1-Wire is a registered trademark of Dallas Semiconductor.

PIN ASSIGNMENT

| VCC | Щ | 1 | \bigcirc | 16 | III VCC |
|-----|---|---|------------|----|-----------|
| IRQ | Ш | 2 | | 15 | III X1 |
| RST | Щ | 3 | | 14 | III X2 |
| DQ | Щ | 4 | | 13 | III GND |
| I/O | Ш | 5 | | 12 | III NC |
| CLK | Щ | 6 | | 11 | III 1HZ |
| NC | Щ | 7 | | 10 | U VBATO |
| GND | Щ | 8 | | 9 | III VBATB |
| | | | | | |

DS2404

EconoRAM Time Chip

16-PIN DIP (300 MIL) 16-PIN SO (300 MIL) 16-PIN SSOP (208 MIL)

See Mechanical Drawings Section

PIN DESCRIPTION

| V _{CC} | - 2.8 to 5.5V |
|---------------------|--|
| | Interrupt Output |
| RST | - 3-Wire Reset Input |
| DQ | - 3-Wire Input/Output |
| I/O | 1-Wire Input/Output |
| CLK | 3-Wire Clock Input |
| NC | No Connection |
| GND | – Ground |
| V _{BATB} | Battery Backup Input |
| V _{BATO} | - Battery Operate Input |
| 1Hz | 1Hz Output |
| X ₁ , X2 | Crystal Connections |
| | |

The DS2404 features can be used to create a stopwatch, alarm clock, time and date stamp, logbook, hour meter, calendar, system power-cycle timer, expiration timer, and event scheduler.

| DETAILED | PIN DESCR | IFTION |
|----------|-------------------|--|
| PIN | SYMBOL | DESCRIPTION |
| 1,16 | V _{CC} | Power input pins for V_{CC} operate mode. 2.8V to 5.5V operation. Either |
| | | one can be used for V_{CC} . Only one is required for normal operation. (See |
| | | V _{BATO} pin description and "Power Control" section). |
| 2 | ĪRQ | Interrupt output pin. Open drain. |
| 3 | RST | Reset input pin for 3-wire operation. (See "Parasite Power" section.) |
| 4 | DQ | Data input/output pin for 3-wire operation. |
| 5 | I/O | Data input/output for 1-Wire operation: Open drain. (See "Parasite |
| | | Power" section.) |
| 6 | CLK | Clock input pin for 3-wire operation. |
| 7,12 | NC | No connection pins. |
| 8,13 | GND | Ground pin. Either pin can be used for ground. |
| 9 | V _{BATB} | Battery backup input pin. Battery voltage can be 2.8V to 5.5V. (See |
| | | V _{BATO} pin description and "Power Control" section.) |
| 10 | V _{BATO} | Battery operate input pin for 2.8V to 5.5V operation. The V _{CC} & |
| | | V_{BATB} pins must be grounded when this pin is used to power the chip. |
| | | (See "Power Control" section.) |
| 11 | 1Hz | 1Hz square wave output: Open drain. |
| 14,15 | X1,X2 | Crystal pins. Connections for a standard 32.768kHz quartz crystal, |
| | | EPSON part number C-002RX or C-004R (be sure to request 6pF load |
| | | capacitance). |
| | | NOTE: X1 and X2 are very high impedance nodes. It is recommended |
| | | that they and the crystal be guard-ringed with ground and that high |
| | | frequency signals be kept away from the crystal area. See Figure 18 and |
| | | Application Note 58 for details. |
| | | |

DETAILED PIN DESCRIPTION

OVERVIEW

The DS2404 has four main data components: 1) 64-bit lasered ROM, 2) 256-bit scratchpad, 3) 4096-bit SRAM, and 4) timekeeping registers. The timekeeping section utilizes an on-chip oscillator that is connected to an external 32.768kHz crystal. The SRAM and timekeeping registers reside in one contiguous address space referred to hereafter as memory. All data is read and written least significant bit first.

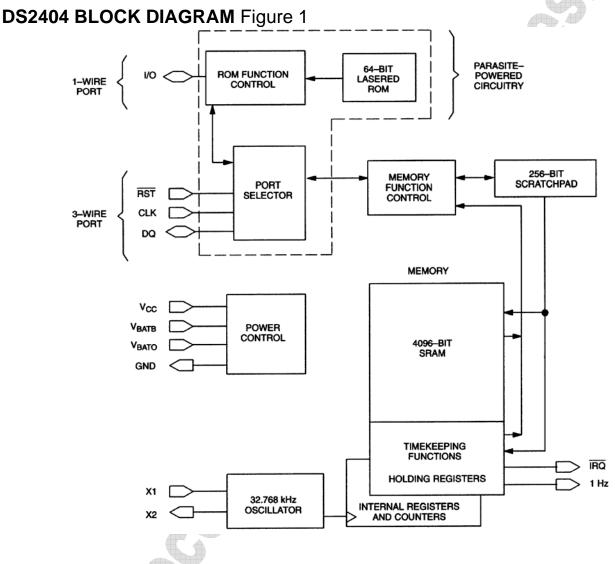
Two communication ports are provided a 1-Wire port and a 3-wire port. A port selector determines which of the two ports is being used. The communication ports and the ROM are parasite-powered via I/O, $\overline{\text{RST}}$, or V_{CC}. This allows the ROM to be read in the absence of power. The ROM data is accessible only through the 1-Wire port. The scratchpad and memory are accessible via either port.

If the 3-wire port is used, the master provides one of four memory function commands: 1) read memory, 2) read scratchpad, 3) write scratchpad, or 4) copy scratchpad. The only way to write memory is to first write the scratchpad and then copy the scratchpad data to memory. (See Figure 6.)

If the 1-Wire port is used, the memory functions will not be available until the ROM function protocol has been established. This protocol is described in the ROM functions flow chart (Figure 9). The master must first provide one of five ROM function commands: 1) read ROM, 2) match ROM, 3) search ROM,

4) skip ROM or 5) search interrupt. After a ROM function sequence has been successfully executed, the memory functions are accessible and the master may then provide any one of the four memory function commands (Figure 6).

The "Power Control" section provides for two basic power configurations: battery operate mode and V_{CC} operate mode. The battery operate mode utilizes one supply connected to V_{BATO} . The V_{CC} operate mode may utilize two supplies; the primary supply connects to V_{CC} and a backup supply connects to V_{BATB} .



COMMUNICATION PORTS

Two communication ports are provided: a 1-Wire and a 3-wire port. The advantages of using the 1-Wire port are as follows: 1) provides access to the 64-bit lasered ROM, 2) consist of a single communication signal (I/O), and 3) multiple devices may be connected to the 1-Wire bus. The 1-Wire bus has a maximum data rate of 16.3kbits/s and requires one $5k\Omega$ external pull-up.

The 3-wire port consists of three signals: $\overline{\text{RST}}$, CLK, and DQ. $\overline{\text{RST}}$ is an enable input, DQ is bidirectional serial data, and the CLK input is used to clock in or out the serial data. The advantages of using the 3-wire port are 1) high data transfer rate (2MHz), 2) simple timing, and 3) no external pull-up required.

Port selection is accomplished on a first-come, first-serve basis. Whichever port comes out of reset first will obtain control. For the 3-wire port, this is done by bringing $\overline{\text{RST}}$ high. For the 1-Wire port, this is done on the first falling edge of I/O after the reset and presence pulses. (See "1-Wire Signaling" section.) More information on how to arbitrate port access is found in section "Device Operation Modes" later in this document.

PARASITE POWER

The block diagram (Figure 1) shows the parasite-powered circuitry. This circuitry "steals" power whenever the I/O, \overline{RST} , or V_{CC} pins are high. When using the 1-Wire port in battery operate mode, \overline{RST} and V_{CC} provide no power since they are low. However, I/O will provide sufficient power as long as the specified timing and voltage requirements are met. The advantages of parasite power are two-fold: 1) by parasiting off these pins, battery power is conserved and 2) the ROM may be read in absence of normal power. For instance, in battery-operate mode, if the battery fails, the ROM may still be read normally.

In battery-backed mode, if V_{CC} fails, the port switches in the battery but inhibits communication. The ROM may still be read normally over the 1-Wire port if \overline{RST} is low.

64-BIT LASERED ROM

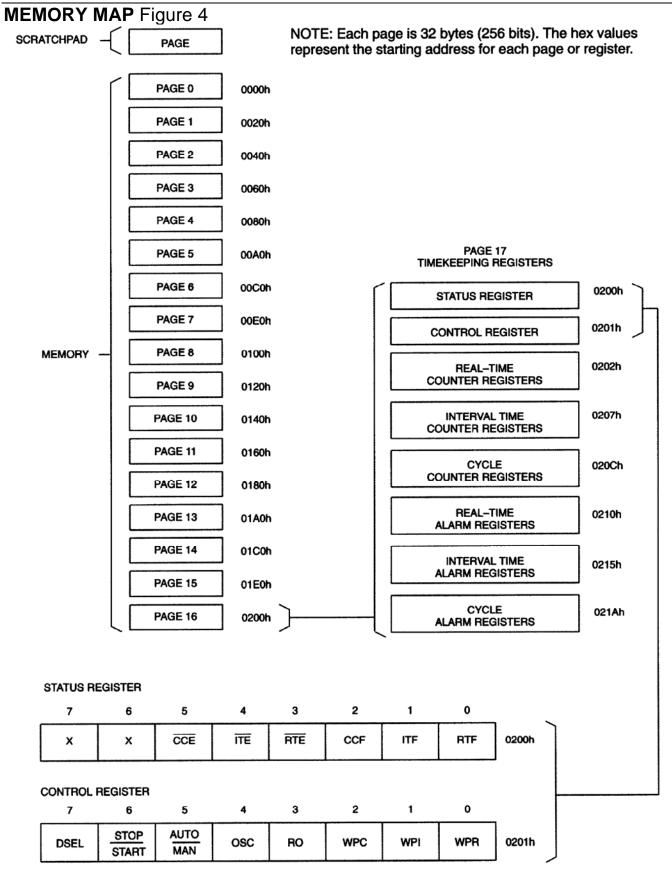
Each DS2404 contains a unique ROM code that is 64 bits long. The first eight bits are a 1-Wire family code (DS2404 code is 04h). The next 48 bits are a unique serial number. The last eight bits are a CRC of the first 56 bits. (See Figure 2.)

The 1-Wire CRC is generated using a polynomial generator consisting of a shift register and XOR gates as shown in Figure 3. The polynomial is $X^8 + X^5 + X^4 + 1$. Additional information about the Dallas 1-Wire Cyclic Redundancy Check is available in Application Note 27, "Understanding and Using Cyclic Redundancy Checks with Dallas Semiconductor <u>i</u>Button Products".

The shift register bits are initialized to zero. Then starting with the least significant bit of the family code, one bit at a time is shifted in. After the 8th bit of the family code has been entered, then the serial number is entered. After the 48th bit of the serial number has been entered, the shift register contains the CRC value. Shifting in the eight bits of CRC should return the shift register to all zeros.

CRC SERIAL NUMBER DS2404 FAMILY CODE 8 BITS **48-BIT UNQUE NUMBER** 04h **MSB** LSB 1-WIRE CRC CODE Figure 3 INPUT $Polynomial = X^8 + X^5 + X^4 + 1$ 6TH 7TH 8TH 5TH 3RD 4TH 1ST 2ND XOR XOR XOR STAGE STAGE STAGE STAGE STAGE STAGE STAGE STAGE χ8 X6 χ7 χз X4 Х2 X0 χı χ²

64-BIT LASERED ROM Figure 2



MEMORY

The memory map in Figure 4 shows a page (32 bytes) called the scratchpad and 17 pages called memory. Pages 0 through 15 each contain 32 bytes which make up the 4096-bit SRAM. Page 16 has only 30 bytes which contain the timekeeping registers.

The scratchpad is an additional page of memory that acts as a buffer when writing to memory. Data is first written to the scratchpad where it can be read back. After the data has been verified, a copy scratchpad command will transfer the data to memory. This process ensures data integrity when modifying the memory.

TIMEKEEPING

A 32.768kHz crystal oscillator is used as the time base for the timekeeping functions. The oscillator can be turned on or off by an enable bit in the control register. The oscillator must be on for the real-time clock, interval timer, cycle counter and 1Hz output to function.

The timekeeping functions are double buffered. This feature allows the master to read time or count without the data changing while it is being read. To accomplish this, a snapshot of the counter data is transferred to holding registers which the user accesses. This occurs after the eighth bit of the Read Memory Function command.

Real-Time Clock

The real-time clock is a 5-byte binary counter. It is incremented 256 times per second. The least significant byte is a count of fractional seconds. The upper four bytes are a count of seconds. The real-time clock can accumulate 136 years of seconds before rolling over. Time/date is represented by the number of seconds since a reference point which is determined by the user. For example, 12:00A.M., January 1, 1970 could be a reference point.

Interval Timer

The interval timer is a 5-byte binary counter. When enabled, it is incremented 256 times per second. The least significant byte is a count of fractional seconds. The interval timer can accumulate 136 years of seconds before rolling over. The interval timer has two modes of operation which are selected by the AUTO/MAN bit in the control register. In the auto mode, the interval timer will begin counting after the I/O line has been high for a period of time determined by the DSEL bit in the control register. Similarly, the interval timer will stop counting after the I/O line has been low for a period of time determined by the DSEL bit. In the manual mode, time accumulation is controlled by the STOP/START bit in the control register.

NOTE: For auto mode operation, the high level on the I/O pin must be greater than or equal to 70% of V_{CC} or V_{BATO} .

Cycle Counter

The cycle counter is a 4-byte binary counter. It increments after the falling edge of the I/O line if the appropriate I/O line timing has been met. This timing is selected by the DSEL bit in the control register. (See "Status/ Control" section).

NOTE: For cycle counter operation, the high level on the I/O pin must be greater than or equal to 70% of $V_{CC}\, or \, V_{BATO}$.

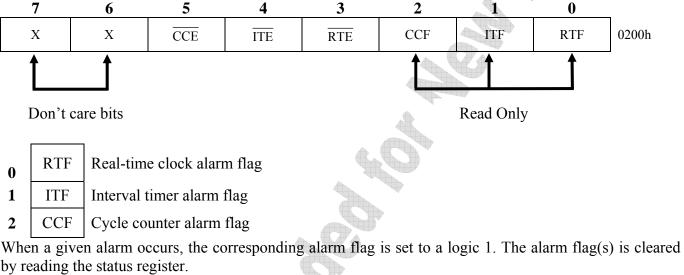
Alarm Registers

The alarm registers for the real-time clock, interval timer, and cycle counter all operate in the same manner. When the value of a given counter equals the value in its associated alarm register, the appropriate flag bit is set in the status register. If the corresponding interrupt enable bit(s) in the status register is set, an interrupt is generated. If a counter and its associated alarm register are write protected when an alarm occurs, access to the device becomes limited. (See "Status/Control", "Interrupts", and the "Programmable Expiration" sections.)

STATUS/CONTROL REGISTERS

The status and control registers are the first two bytes of page 16 (see "Memory Map", Figure 4).

Status Register



by reading the status register.

| 3 | RTE | Real-time interrupt enable |
|---|-----|---------------------------------|
| 4 | ITE | Interval timer interrupt enable |
| 5 | CCE | Cycle counter interrupt enable |

Writing any of the interrupt enable bits to a logic 0 will allow an interrupt condition to be generated when its corresponding alarm flag is set (see "Interrupts" section).

Control Register

| | | 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 | |
|---|--|----|---------------|--------------|-----|----|-----|-----|-----|-------|
| | DS | EL | STOP START | AUTO MAN. | OSC | RO | WPC | WPI | WPR | 0201h |
| 0 WPR Write protect real-time clock/alarm registers | | | | | | | - | | | |
| | 1 WPI Write protect interval timer/alarm registers | | | | | | | | | |
| 2 WPC Write protect cycle counter/alarm registers | | | | | | | | | | |

Setting a write protect bit to a logic 1 will permanently write protect the corresponding counter and alarm registers, all write protect bits, and additional bits in the control register. The write protect bits can not be written in a normal manner (see "Write Protect/Programmable Expiration" section).

If a programmable expiration occurs and the read only bit is set to a logic 1, then the DS2404 becomes read only. If a programmable expiration occurs and the read only bit is a logic 0, then only the 64-bit lasered ROM can be accessed (see "Write Protect/Programmable Expiration" section).

This bit controls the crystal oscillator. When set to a logic 1, the oscillator will start operation. When the oscillator bit is a logic 0, the oscillator will stop.

Automatic/Manual Mode

When this bit is set to a logic 1, the interval timer is in automatic mode. In this mode, the interval timer is enabled by the I/O line. When this bit is set to a logic 0, the interval timer is in manual mode. In this mode the interval timer is enabled by the $STOP/\overline{START}$ bit.

If the interval timer is in manual mode, the interval timer will start counting when this bit is set to a logic 0 and will stop counting when set to a logic 1. If the interval timer is in automatic mode, this bit has no effect.

7 DSEL Delay Select Bit

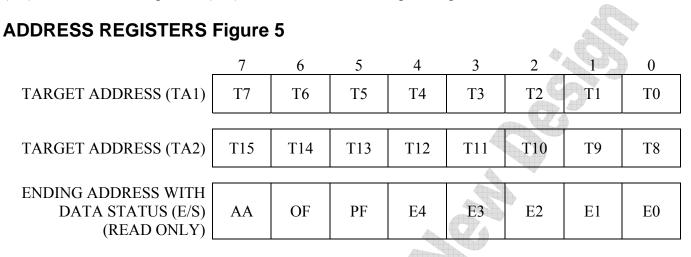
This bit selects the delay that it takes for the cycle counter and the interval timer (in auto mode) to see a transition on the I/O line. When this bit is set to a logic 1, the delay time is 123 + 2 ms. This delay allows communication on the I/O line without starting or stopping the interval timer and without incrementing the cycle counter. When this bit is set to a logic 0, the delay time is 3.5 ± 0.5 ms.

MEMORY FUNCTION COMMANDS

The "Memory Function Flow Chart" (Figure 6) describes the protocols necessary for accessing the memory. Two examples follow the flowchart. Three address registers are provided as shown in Figure 5. The first two registers represent a 16-bit target address (TA1, TA2). The third register is the ending offset/data status byte (E/S).

The target address points to a unique byte location in memory. The first five bits of the target address (T4:T0) represent the byte offset within a page. This byte offset points to one of 32 possible byte locations within a given page. For instance, 00000b points to the first byte of a page where as 11111b would point to the last byte of a page.

The third register (E/S) is a read only register. The first five bits (E4: E0) of this register are called the ending offset. The ending offset is a byte offset within a page. Bit 5 (PF) is the partial byte flag. Bit 6 (OF) is the overflow flag. Bit 7 (AA) is the authorization accepted flag.



Write Scratchpad Command [0Fh]

After issuing the write scratchpad command, the user must first provide the 2–byte target address, followed by the data to be written to the scratchpad. The data will be written to the scratchpad starting at the byte offset (T4:T0). The ending offset (E4: E0) will be the byte offset at which the host stops writing data. The maximum ending offset is 11111b (31d). If the host attempts to write data past this maximum offset, the overflow flag (OF) will be set and the remaining data will be ignored. If the user writes an incomplete byte and an overflow has not occurred, the partial byte flag (PF) will be set.

Read Scratchpad Command [AAh]

This command may be used to verify scratchpad data and target address. After issuing the read scratchpad command, the user may begin reading. The first two bytes will be the target address. The next byte will be the ending offset/data status byte (E/S) followed by the scratchpad data beginning at the byte offset (T4: T0). The user may read data until the end of the scratchpad after which the data read will be all logic 1's.

Copy Scratchpad [55h]

This command is used to copy data from the scratchpad to memory. After issuing the copy scratchpad command, the user must provide a 3-byte authorization pattern. This pattern must exactly match the data contained in the three address registers (TA1, TA2, E/S, in that order). If the pattern matches, the AA (Authorization Accepted) flag will be set and the copy will begin. At this point, the part will go into a T_X mode, transmitting a logic 1 to indicate the copy is in progress. A logic 0 will be transmitted after the data has been copied. Any attempt to reset the part will be ignored while the copy is in progress. Copy typically takes 30 μ s.

The data to be copied is determined by the three address registers. The scratchpad data from the beginning offset through the ending offset, will be copied to memory, starting at the target address. Anywhere from 1 to 32 bytes may be copied to memory with this command. Whole bytes are copied even if only partially written. The AA flag will be cleared only by executing a write scratchpad command.

Υ

Y

MASTER TX MEMORY FUNCTION COMMAND 0Fh AAh 55h F0h Ν Ν Ν READ COPY READ WRITE MEMORY SCRATCHPAD, SCRATCHPAD SCRATCHPAD N γ Y γ MASTER RX MASTER TX MASTER TX TA1 (T7:T0) TA1 (T7:T0) TA1 (T7:T0) MASTER TX TA1 (T7:T0) MASTER RX MASTER TX MASTER TX TA2 (T15:T8) TA2 (T15:T8) TA2 (T15:T8) MASTER TX TA2 (T15:T8) MASTER RX ENDING MASTER TX DS2404 SETS SCRATCHPAD OFFSET/DATA STATUS BYTE (E/S) E/S BYTE OFFSET=(T4:T0) AND CLEARS (PF, OF, AA) DS2404 SETS MEMORY ADDRESS=(T15:T0) DS2404 SETS Ν MASTER TX DATA BYTE SCRATCHPAD AUTHORIZATION OFFSET=(T4:T0) TO SCRATCHPAD OFFSET CODE MATCH MASTER RX DATA BYTE FROM Υ MEMORY ADDRESS MASTER RX DATA DS2404 SETS BYTE FROM (E4:E0)=SCRATCHPAD AA=1 SCRATCHPAD OFFSET OFFSET MASTER TX DS2404 TX "1"s RESET MASTER TX Y RESET MASTER TX INCREMENT MEMORY Ν RESET DS2404 COPIES INCREMENT SCRATCHPAD ADDRESS Ν SCRATCHPAD DATA TO MEMORY INCREMENT Ν OFFSET SCRATCHPAD MEMORY OFFSET ADDRESS Ν SCRATCHPAD =21Dh OFFSET DS2404 N SCRATCHPAD TX "0"s =11111b OFFSET =11111b Y MASTER RX "1"s MASTER TX MASTER RESET Υ MASTER TX RX "1"s DATA PARTIAL OF=1 N BYTE MASTER TX WRITTEN RESET

MEMORY FUNCTION FLOW CHART Figure 6

Y

DS2404 TX PRESENCE

PULSE (SEE FIGURE 9)

WIRE

PORT

SELECTED

PF=1

Ν

Y

N

MASTER TX RESET

Read Memory [F0h]

The read memory command may be used to read the entire memory. After issuing the command, the user must provide the 2-byte target address. After the two bytes, the user reads data beginning from the target address and may continue until the end of memory, at which point logic 1's will be read. It is important to realize that the target address registers will contain the address provided. The ending offset/data status byte is unaffected.

The hardware of the DS2404 provides a means to accomplish error-free writing to the memory section. To safeguard reading data in the 1-Wire environment and to simultaneously speed up data transfers, it is recommended to packetize data into data packets of the size of one memory page each. Such a packet would typically store a 16-bit CRC with each page of data to ensure rapid, error-free data transfers that eliminate having to read a page multiple times to determine if the received data is correct or not. (See the Book of DS19xx <u>i</u>Button Standards, Chapter 7 for the recommended file structure to be used with the 1-Wire environment.)

MEMORY FUNCTION EXAMPLES

Example 1: Write one page of data to page 15 Read page 15 (3-wire port)

| MASTER MODE | DATA(LSB FIRST) | COMMENTS |
|-------------|----------------------------|--------------------------------------|
| TX | Reset | Master pulses RST low |
| TX | 0Fh | Issue "write scratchpad" command |
| TX | E0h | TA1, beginning offset=0 |
| TX | 01h | TA2, address=01E0h |
| TX | <32 data bytes> | Write 1 page of data to scratchpad |
| TX | Reset 📃 💽 | Master pulses RST low |
| TX | AAh | Issue "read scratchpad" command |
| RX | E0h | Read TA1, beginning offset=0 |
| RX | 01h | Read TA2, address=01E0h |
| RX | 1Fh | Read E/S, ending offset=31d, flags=0 |
| RX | <32 data bytes> | Read scratchpad data and verify |
| TX | Reset | Master pulses RST low |
| TX | 55h | Issue "copy scratchpad" command |
| TX | E0h | TA1 |
| TX | 01h | TA2 AUTHORIZATION CODE |
| TX | 1Fh | E/S |
| RX | <busy indicator=""></busy> | Wait until DQ=0 (~30 µs typical) |
| TX | Reset | Master pulses RST low |
| TX | F0h | Issue "read memory" command |
| TX | E0h | TA1, beginning offset=0 |
| TX | 01h | TA2, address=01E0h |
| RX | <32 data bytes> | Read memory page 15 and verify |
| TX | Reset | Master pulses RST low, done |

NOTE: The ROM function commands do not apply to the 3-wire port. After \overline{RST} is at a high level, the device expects to receive a memory function command.

Example 2: Write two data bytes to memory locations 0026h and 0027h (the seventh and eighth byte of page 1). Read entire memory (1-Wire port).

| MASTER MODE | DATA(LSB FIRST) | COMMENTS | | |
|-------------|-----------------|-------------------------------------|--|--|
| TX | Reset | reset pulse (480–960 μs) | | |
| RX | Presence | presence pulse | | |
| TX | CCh | Issue "skip ROM" command | | |
| TX | 0Fh | Issue "write scratchpad" command | | |
| TX | 26h | TA1, beginning offset=6 | | |
| TX | 00h | TA2, address=0026h | | |
| TX | <2 data bytes> | Write 2 bytes of data to scratchpad | | |
| TX | Reset | reset pulse | | |
| RX | Presence | presence pulse | | |
| TX | CCh | Issue "skip ROM" command | | |
| TX | AAh | Issue "read scratchpad" command | | |
| RX | 26h | Read TA1, beginning offset=6 | | |
| RX | 00h | Read TA2, address=0026h | | |
| RX | 07h | Read E/S, ending offset=7, flags=0 | | |
| RX | <2 data bytes> | Read scratchpad data and verify | | |
| TX | Reset | reset pulse | | |
| RX | Presence | presence pulse | | |
| TX | CCh | Issue "skip ROM" command | | |
| TX | 55h | Issue "copy scratchpad" command | | |
| TX | 26h | TA1 | | |
| TX | 00h | TA2 AUTHORIZATION CODE | | |
| TX | 07h | E/S | | |
| TX | Reset | reset pulse | | |
| RX | Presence | presence pulse | | |
| TX | CCh | Issue "skip ROM" command | | |
| TX | F0h | Issue "read memory" command | | |
| ТХ | 00h | TA1, beginning offset=0 | | |
| TX | 00h | TA2, address=0000h | | |
| RX | <542 bytes> | Read entire memory | | |
| TX | Reset | reset pulse | | |
| RX | Presence | presence pulse, done | | |
| | | | | |

WRITE PROTECT/PROGRAMMABLE EXPIRATION

The write protect bits (WPR, WPI, WPC) provide a means of write protecting the timekeeping data and limiting access to the DS2404 when an alarm occurs (programmable expiration).

The write protect bits may not be written by performing a single copy scratchpad command. Instead, to write these bits, the copy scratchpad command must be performed three times. Please note that the AA bit will be set, as expected, after the first copy command is successfully executed. Therefore, the authorization pattern for the second and third copy command should have this bit set. The read scratchpad command may be used to verify the authorization pattern.

The write protect bits, once set, permanently write protects their corresponding counter and alarm registers, all write protect bits, and certain control register bits as shown in Figure 7. The time/count registers will continue to count if the oscillator is enabled. If the user wishes to set more than one write protect bit, the user must set them at the same time. Once a write protect bit is set it cannot be undone, and the remaining write protect bits, if not set, cannot be set.

The programmable expiration takes place when one or more write protect bits have been set and a corresponding alarm occurs. If the RO (read only) bit is set, only the read scratchpad and read memory function commands are available. If the RO bit is a logic "0", no memory function commands are available. The ROM functions are always available.

| WRITE PROTECT BIT SET: | WPR | WPI | WPC |
|------------------------|-----------------|---------------------|---------------------|
| Data Protected from | Real Time Clock | Interval Timer | Cycle Counter |
| User Modification: | Real Time Alarm | Interval Time Alarm | Cycle Counter Alarm |
| | WPR | WPR | WPR |
| | WPI | WPI | WPI |
| | WPC | WPC | WPC |
| | RO | RO | RO |
| | OSC * | OSC * | OSC * |
| | | STOP/START ** | DSEL |
| | | AUTO/MAN | |

WRITE PROTECT CHART Figure 7

* Becomes write "1" only, i.e., once written to a logic "1", may not be written back to a logic "0".

** Forced to a logic "0".

1-WIRE BUS SYSTEM

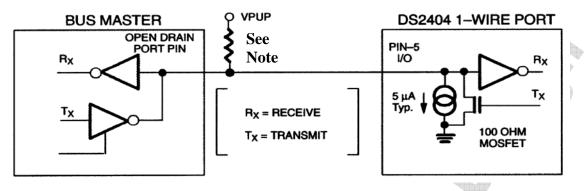
The 1-Wire bus is a system which has a single bus master and one or more slaves. In most instances the DS2404 behaves as a slave. The exception is when the DS2404 generates an interrupt due to a timekeeping alarm. The discussion of this bus system is broken down into three topics: hardware configuration, transaction sequence, and 1-Wire signaling (signal types and timing). The 1-Wire protocol defines bus transactions in terms of the bus state during specific time slots that are initiated on the falling edge of sync pulses from the bus master. For a more detailed protocol description, refer to Chapter 4 of the Book of DS19XX <u>i</u>Button Standards.

HARDWARE CONFIGURATION

The 1-Wire bus has only a single line by definition; it is important that each device on the bus be able to drive it at the appropriate time. To facilitate this, each device attached to the 1-Wire bus must have open drain or 3-state outputs. The 1-Wire port of the DS2404 (I/O pin 5) is open drain with an internal circuit equivalent to that shown in Figure 8. A multidrop bus consists of a 1-Wire bus with multiple slaves attached. The 1-Wire bus has a maximum data rate of 16.3k bits per seconds. Depending on 1-Wire communication speed and bus load characteristics, the optimal pull-up resistor value will be in the 1.5 k Ω to 5 k Ω range.

The idle state for the 1-Wire bus is high. If for any reason a transaction needs to be suspended, the bus MUST be left in the idle state if the transaction is to resume. If this does not occur and the bus is left low for more than $120 \,\mu$ s, one or more of the devices on the bus may be reset.

HARDWARE CONFIGURATION Figure 8



NOTE:

Depending on 1-Wire communication speed and bus load characteristics, the optimal pull-up resistor value will be in the 1.5 k Ω range to 5 k Ω range.

TRANSACTION SEQUENCE

The protocol for accessing the DS2404 via the 1-Wire port is as follows:

- Initialization
- ROM Function Command
- Memory Function Command
- Transaction/Data

INITIALIZATION

All transactions on the 1-Wire bus begin with an initialization sequence. The initialization sequence consists of a reset pulse transmitted by the bus master followed by presence pulse(s) transmitted by the slave(s). The presence pulse lets the bus master know that the DS2404 is on the bus and is ready to operate. For more details, see the "1-Wire Signaling" section.

ROM FUNCTION COMMANDS

Once the bus master has detected a presence, it can issue one of the five ROM function commands. All ROM function commands are eight bits long. A list of these commands follows (refer to flowchart in Figure 9):

Read ROM [33h]

This command allows the bus master to read the DS2404's 8-bit family code, unique 48-bit serial number, and 8-bit CRC. This command can only be used if there is a single DS2404 on the bus. If more than one slave is present on the bus, a data collision will occur when all slaves try to transmit at the same time (open drain will produce a wired-AND result). The resultant family code and 48-bit serial number will usually result in a mismatch of the CRC.



Match ROM [55h]

The match ROM command, followed by a 64-bit ROM sequence, allows the bus master to address a specific DS2404 on a multidrop bus. Only the DS2404 that exactly matches the 64-bit ROM sequence will respond to the following memory function command. All slaves that do not match the 64-bit ROM sequence will wait for a reset pulse. This command can be used with a single or multiple devices on the bus.

Skip ROM [CCh]

This command can save time in a single drop bus system by allowing the bus master to access the memory functions without providing the 64-bit ROM code. If more than one slave is present on the bus and a read command is issued following the Skip ROM command, data collision will occur on the bus as multiple slaves transmit simultaneously (open drain pulldowns will produce a wired-AND result).

Search ROM [F0h]

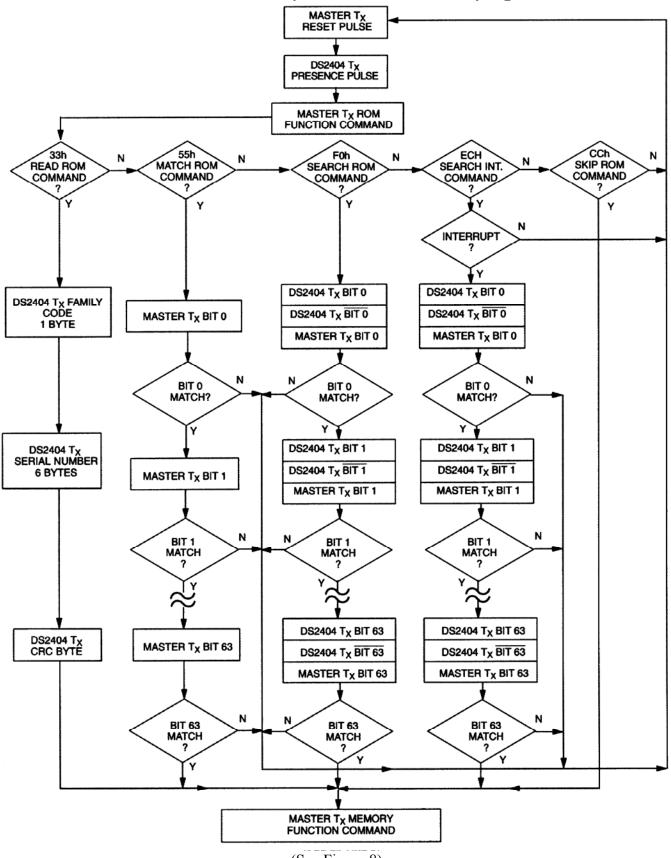
When a system is initially brought up, the bus master might not know the number of devices on the 1-Wire bus or their 64-bit ROM codes. The search ROM command allows the bus master to use a process of elimination to identify the 64-bit ROM codes of all slave devices on the bus. The search ROM process is the repetition of a simple 3-step routine: read a bit, read the complement of the bit, then write the desired value of that bit. The bus master performs this simple, 3-step routine on each bit of the ROM. After one complete pass, the bus master knows the contents of the ROM in one device. The remaining number of devices and their ROM codes may be identified by additional passes. See Chapter 5 of the Book of DS19xx <u>i</u>Button Standards for a comprehensive discussion of a search ROM, including an actual example.

Search Interrupt [ECh]

This ROM command works exactly as the normal ROM Search, but it will identify only devices with interrupts that have not yet been acknowledged.

A CORRECT

ROM FUNCTIONS FLOW CHART (1-WIRE PORT ONLY) Figure 9



(See Figure 8)

1-WIRE SIGNALING

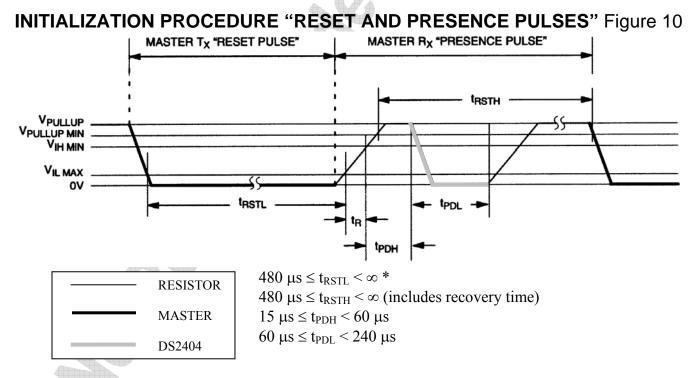
The DS2404 requires strict protocols to ensure data integrity. The protocol consists of five types of signaling on one line: Reset Sequence with reset pulse and presence pulse, write 0, write 1, Read Data and interrupt pulse. All these signals except presence pulse and interrupt pulse are initiated by the bus master.

The initialization sequence required to begin any communication with the DS2404 is shown in Figure 10. A reset pulse followed by a presence pulse indicates the DS2404 is ready to send or receive data given the correct ROM command and memory function command.

The bus master transmits (T_X) a reset pulse (t_{RSTL} , minimum of 480 µs). The bus master then releases the line and goes into receive mode (R_X). The 1-Wire bus is pulled to a high state via the pull-up resistor. After detecting the rising edge on the date line, the DS2404 waits (t_{PDH} , 15-60 µs) and then transmits the presence pulse (t_{PDL} , 60 - 240 µs). There are special conditions if interrupts are enabled where the bus master must check the state of the 1-Wire bus after being in the R_X mode for 480 µs. These conditions will be discussed in the "Interrupt" section.

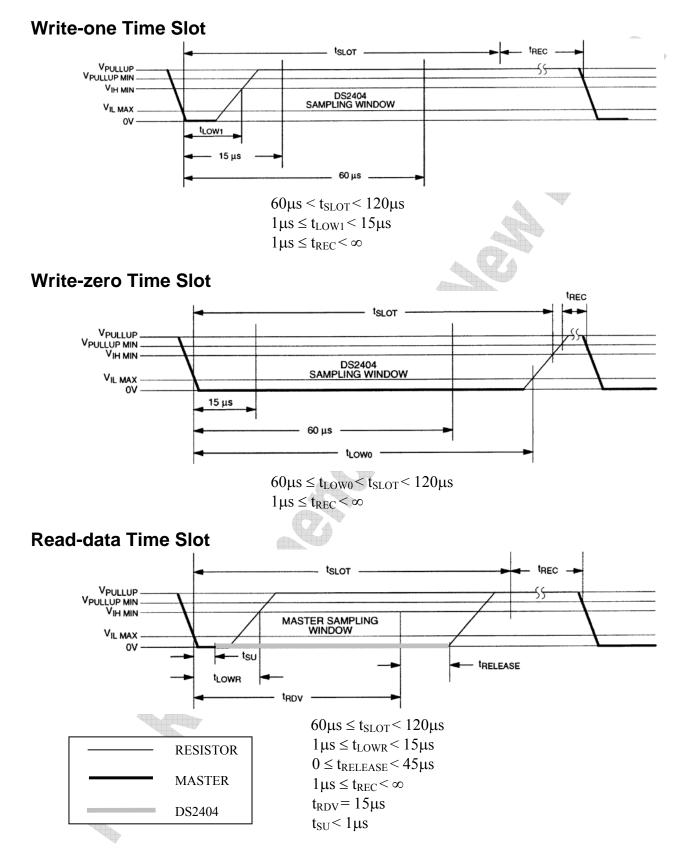
READ/WRITE TIME SLOTS

The definitions of write and read time slots are illustrated in Figure 11. All time slots are initiated by the master driving the data line low. The falling edge of the data line synchronizes the DS2404 to the master by triggering a delay circuit in the DS2404. During write time slots, the delay circuit determines when the DS2404 will sample the data line. For a read data time slot, if a "0" is to be transmitted, the delay circuit determines how long the DS2404 will hold the data line low overriding the 1 generated by the master. If the data bit is a "1", the device will leave the read data time slot unchanged.



* In order not to mask interrupt signaling by other devices on the 1-Wire bus, $t_{RSTL} + t_R$ should always be less than 960 μ s.

READ/WRITE TIMING DIAGRAM Figure 11



Interrupts

If the DS2404 detects an alarm condition, it will automatically set the corresponding alarm flag (CCF, ITF or RTF) in the Status Register. If the flag's corresponding interrupt bit ($\overline{\text{RST}}$, $\overline{\text{ITE}}$ or $\overline{\text{RTE}}$) is enabled (logic 0) an interrupt condition begins as the alarm goes off. The DS2404 signals the interrupt condition by pulling the open drain $\overline{\text{IRQ}}$ output low. The interrupt condition ceases when the alarm flags are cleared (i.e., the interrupt is acknowledged by reading the Status Register, address 200H) or if the corresponding interrupt enable bit is disabled (set to logic 1).

Interrupts can also be generated on the 1-Wire port. Since communication and interrupt signaling share the same pin, one has to distinguish between two types of interrupts: spontaneous interrupts, called type 1, and delayed interrupts type 2. Spontaneous interrupts that have not yet occurred need to be (re-) armed by a reset pulse after all communication on the 1-Wire bus has finished. A single falling slope on the 1-Wire bus will disarm this type of interrupt. If an alarm condition occurs while the device is disarmed, at first a type 2 interrupt will be produced.

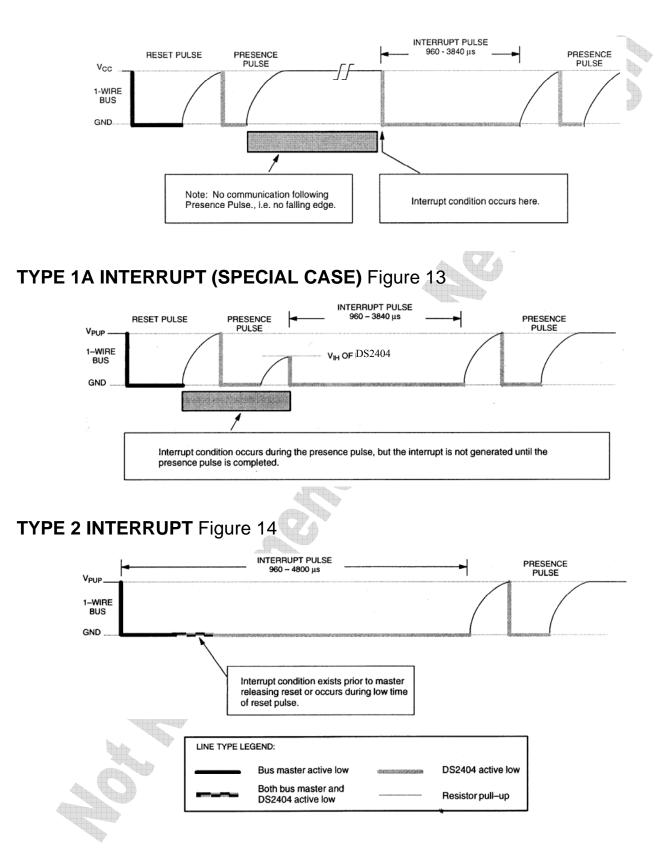
Spontaneous interrupts are signaled by the DS2404 by pulling the data line low for 960 to 3840 µs as the interrupt condition begins (Figure 12). After this long low pulse a presence pulse will follow. If the alarm condition occurs just after the master has sent a reset pulse, i.e., during the high or low time of the presence pulse, the DS2404 will not assert its Interrupt Pulse until the presence pulse is finished (Figure 13).

If the DS2404 cannot assert a spontaneous interrupt, either because the data line was not pulled high, communication was in progress, or the interrupt was not armed, it will extend the next reset pulse to a total length of 960 to 3840 μ s (delayed interrupt). If the alarm condition occurs during the reset low time of the reset pulse, the DS2404 will immediately assert its interrupt pulse; thus the total low time of the pulse can be extended up to 4800 μ s (Figure 14). If a DS2404 with a not previously signaled alarm detects a power-on cycle on the 1-Wire bus, it will send a presence pulse and wait for the reset pulse sent by the master to extend it and to subsequently issue a presence pulse (Figure 15). As long as an interrupt has not been acknowledged by the master, the DS2404 will continue sending interrupt pulses.

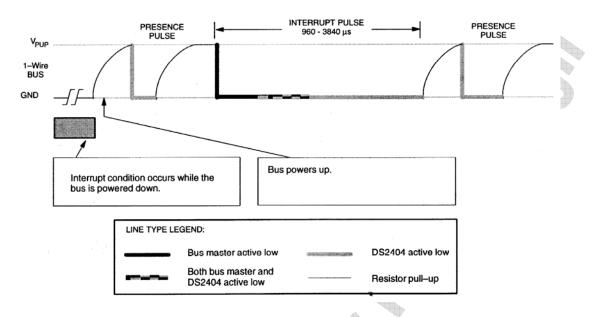
The interrupt signaling discussed so far is valid for the first opportunity the device has to signal an interrupt. It is not required for the master to acknowledge an interrupt immediately. If an interrupt is not acknowledged, the DS2404 will continue signaling the interrupt with every reset pulse. To do so, DS2404 devices of Revision B4 (earlier production parts) will always use the waveform of the Type 2 Interrupt (Figure 14). Devices of Revision B5 (current production) will either use the waveform of the Type 2 Interrupt (Figure 14) or the waveform of the Type 1A Interrupt (Figure 13). The waveform of the Type 2 Interrupt will be observed after a communication to a device other than the interrupting one; after successful communication to the interrupting device (without acknowledging the interrupt) the waveform of the Type 1A Interrupt will be found. The revision code of the DS2404 is appended to the manufacturing date code, which is printed on the top of the package right below the part number.



TYPE 1 INTERRUPT Figure 12



TYPE 2 INTERRUPT (SPECIAL CASE) Figure 15



3-WIRE I/O COMMUNICATIONS

The 3-wire bus is comprised of three signals. These are the \overline{RST} (reset) signal, the CLK (clock) signal, and the DQ (data) signal. All data transfers are initiated by driving the \overline{RST} input high. Driving the RST input low terminates communication. (See Figures 19 and 20.)

A clock cycle is a sequence of a falling edge followed by a rising edge. For data inputs, the data must be valid during the rising edge of a clock cycle. Command bits and data bits are input on the rising edge of the clock and data bits are output on the falling edge of the clock. When reading data from the DS2404, the DQ pin goes to a high impedance state while the clock is high. Taking $\overline{\text{RST}}$ low will terminate any communication and cause the DQ pin to go to a high impedance state.

POWER CONTROL

There are two methods of supplying power to the DS2404, V_{CC} Operate mode with battery backup and Battery Operate mode. If the DS2404 is used in an application where battery backup is not desired, the part must be wired for Battery Operate mode.

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V_{CC} Operate Mode (Battery-Backed)

Figure 16 shows the necessary connections for operating the DS2404 in V_{CC} Operate mode.

V_{cc} OPERATE MODE Figure 16 +5V TYPICAL +5V V_{CC} II Vcc п 1 16 CONNECT PIN 13 2 TO GUARD RING 15 (SEE FIGURE 18) 3 14 GND Ш 13 5 12 6 11 VBATO UNCONNECTED Œ 7 10 VBATB GND 9 +3V TYPICAL V_{CC} Pin 1 & 16 2.8V to 5.5V **V**_{BATB} 2.8V to 5.5V Pin 9 **V**BATO Pin 10 must be unconnected

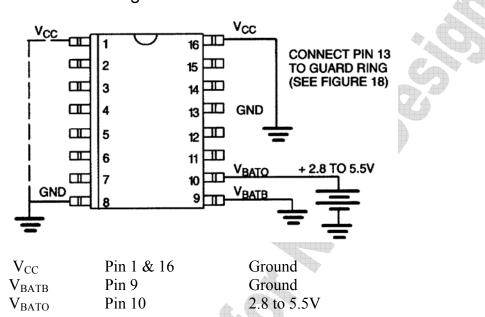
To always allow communication through the 1-Wire or wire port, the voltage on V_{CC} must be approximately 3-wire port, the voltage on V_{CC} must be approximately 0.2V above the voltage on V_{BATB} . Otherwise the DS2404 will retain data, but will not allow any access.

The V_{BATB} pin is normally connected to any standard 3V lithium cell or other energy source. As V_{CC} falls below V_{BATB}, the power switching circuit allows V_{BATB} to provide energy for maintaining clock functionality and data retention. No communication can take place while V_{BATB} is greater than V_{CC}. During power-up, when V_{CC} reaches a value of approximately 0.2V above V_{BATB}, the power switching circuit connects V_{CC} and disconnects V_{BATB}. If the oscillator is on, no communication can take place until V_{CC} has stayed approximately 0.2V above V_{BATB} for 123 ± 2ms. During power-down, the falling V_{CC} must pass the range from V_{BATB} to 0V in no less than 100ns for the power switching circuit to function properly.

Battery Operate Mode

Figure 17 shows the necessary connections for operating the DS2404 in Battery Operate mode.

BATTERY OPERATE MODE Figure 17



The V_{BATO} pin is normally connected to any standard 3 V lithium cell or other energy source. The Battery Operate mode also minimizes the power-consumption in applications where battery backup is not required and the V_{BATO} lead is directly connected to the system's 5V supply.

NOTE:

In Battery Operate mode, the voltage on DQ must never exceed the voltage on V_{BATO} if the 3-wire interface is used. This restriction does not apply to the 1-Wire interface.

DEVICE OPERATION MODES

With its two ports and two power modes the DS2404 can be operated in several ways. While the maximum voltage on the 1-Wire port (I/O) is always 6V, the maximum voltage on the 3-wire port (DQ) depends on the power mode and actual operating voltage. A particular port is selected by setting the control lines to a state that makes the other port inactive. See Table 1 for details.

When using the 3-wire port only and the DS2404 is wired for V_{CC} Operate Mode (Battery Backed) the 1 Wire I/O pin can be used as counter input. This mode requires that the I/O lead is connected to V_{CC} through a 5k Ω (typical) resistor. To enable communication through the 3-wire port a reset/presence sequence has to be performed on the 1-Wire port after the system has powered up.

OPERATION MODES AND CONDITIONS Table 1

| PORT USAGE | BATTERY OPERATE MODE | V _{CC} OPERATE MODE (BATTERY BACKED) | | | | |
|---------------------|---|--|--|--|--|--|
| 1-Wire only | Float RST, I | DQ, CLK or tie to GND | | | | |
| 3-Wire only | DQ Voltage (3-wire) \leq V _{BATO} DQ Voltage (3-wire) \leq V _{CC} +0.3V | | | | | |
| | If unused: float I/O (1-Wire) or tie to GND; if used as counter input: see text | | | | | |
| 1-Wire and 3-wire | DQ Voltage (3-wire) \leq V _{BATO} | DQ Voltage (3-wire) \leq V _{CC} +0.3V | | | | |
| Dual Port Operation | 1-Wire Port: finish each communi | ication with a reset/presence sequence: when | | | | |
| | idle: either keep I/O pulled high through a resistor or pull it low; | | | | | |
| | 3-wire Port: when idle: keep \overline{RST} and CLK low, keep DQ high or low or | | | | | |
| | floating | | | | | |

DUAL PORT OPERATION

The on-chip arbitration logic works on a first-come, first serve principle. Assuming that at one time both ports are idle, the one port that becomes active prior to the other one is granted access. Activity on the 3-wire port begins as the voltage level on the \overline{RST} input changes from low to high. The 1-Wire port is considered active with the first falling edge detected after the presence pulse.

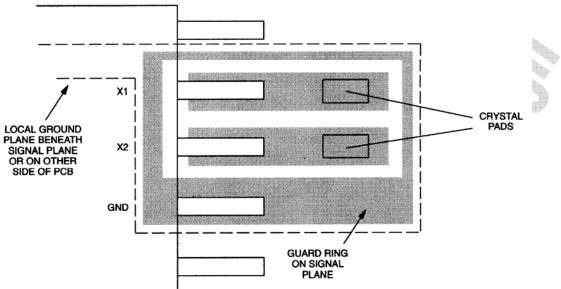
Attempting to communicate with the device through the port that temporarily has no access does not affect communication through the other port. If communication on the 1-Wire port is initiated while the 3-wire port is active, the device will still respond to the reset pulse, but any subsequently transmitted 1-Wire command will be ignored. When reading the ROM or memory, for example, the response will always be 1's, indicating that access was denied. While the 1-Wire port is active, the 3-wire data line DQ is in tristate mode. The always present resistor of approximately $60k\Omega$ pulls DQ low. The micro connected to the 3-wire port will fight against this weak pulldown and, depending on its port characteristics, possibly dominate the logical value on DQ.

Since writing to the memory of the DS2404 requires multiple steps with short periods where both ports are inactive, additional measures are required. To avoid one port overwriting actions initiated by the other port one should do the following:

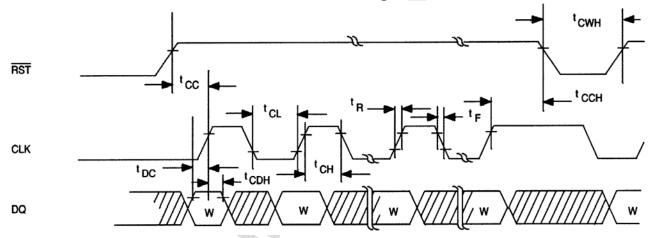
Allow the microcontroller operating the 3-wire port to monitor the activity on the 1-Wire port. This could be done by means of a retriggerable one-shot, for example. The microcontroller should wait for a break of several milliseconds on the 1-Wire port before attempting communication through the 3-wire port.

In addition, data should be organized as data packets with a length byte at the beginning and a CRC check at the end. Whenever one side has finished communication with the DS2404 it should write a token such as a "null-packet" into the scratchpad. A null-packet consists of three bytes that represent a zero length followed by a valid 16-bit CRC. As one port tries to communicate with the device, the first memory function command should be a Read Scratchpad. Communication should only proceed if the null-packet is found. Otherwise communication through the other port is not yet finished and one is likely to interfere if one does not immediately release the port for the communication on the other port to resume. For details on recommended data structures please refer to chapters 7 or 10 of the "Book of DS19xx <u>i</u>Button Standards".

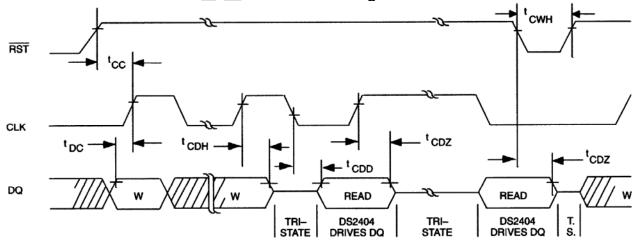
CRYSTAL PLACEMENT ON PCB Figure 18



3-WIRE WRITE DATA TIMING DIAGRAM Figure 19



3-WIRE READ DATA TIMING DIAGRAM Figure 20



400()

ABSOLUTE MAXIMUM RATINGS*

Voltage on DATA to Ground Operating Temperature Range Storage Temperature Range Soldering Temperature -0.5V to +7.0V -40°C to +85°C -55°C to +125°C See J-STD-020A Specification

* This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect reliability.

RECOMMENDED OPERATING CONDITIONS

(-40°C to +85°C)

| PARAMETER | SYMBOL | MIN | ТҮР | MAX | UNITS | NOTES |
|-------------|---------------------|------|-----|----------------------|-------|-------|
| Logic 1 | V _{IH3} | 2.2 | | V _{CC} +0.3 | V | 1 |
| Logic 0 | V _{IL3} | -0.3 | | +0.8 | V | 1 |
| RST Logic 1 | | 2.8 | | 5.5 | V | 1 |
| Supply | V _{CC} | 2.8 | | 5.5 | V | 1 |
| Battery | V _{BATB} , | 2.8 | 3.0 | 5.5 | V | 1,6 |
| | V _{BATO} | | | | | |

DC ELECTRICAL CHARACTERISTICS (1-WIRE PORT)

| (1-WIRE PORT) (-40°C to +85°C; V _{CC} = 5V+ 1 | | | | | | V+ 10%) |
|--|------------------|------|-----|-----------|-------|---------|
| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| Logic 1 | $V_{\rm IH1}$ | 2.2 | | 6.0 | V | 1,9 |
| Logic 0 | V _{IL1} | -0.3 | | +0.8 | V | 1,16 |
| Output Logic Low @ 4mA | V _{OL} | | | 0.4 | V | 1 |
| Output Logic High | V _{OH} | | | V_{PUP} | V | 1,12 |
| Input Load Current | IL | | 5 | | μA | 13 |

DC ELECTRICAL CHARACTERISTICS

| (V _{CC} OP. MODE) | | | (-40°C | ; to +85°C | ;; V _{CC} = 5 | v+ 10%) |
|-----------------------------|------------------|-----|--------|------------|------------------------|---------|
| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| Output Leakage | ILO | | | 1 | μA | 17 |
| Output Current @ 2.4V on DQ | I _{OH} | 3 | | | mA | 18 |
| Output Current @ 0.4V on DQ | I _{OL} | | | -3 | mA | 19 |
| Active Current | I _{CC1} | | | 2 | mA | 5 |
| Standby Current | I _{CC2} | | | 500 | μΑ | 11 |

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DC ELECTRICAL CHARACTERISTICS (BATT. OP. MODE)

| (BATT. OP. MODE) | | | (-40 |)°C to +85 | 5°С; V _{ват} | o= 3.0V) |
|-----------------------------|-------------------|-----|------|------------|-----------------------|----------|
| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| Output Leakage | I _{LO} | | | 1 | μA | 17 |
| Output Current @ 2.4V on DQ | I _{OH} | 1 | | | mA | 18 |
| Output Current @ 0.4V on DQ | I _{OL} | | | -1 | mA | 19 |
| I/O Operate Charge | Q _{BATO} | | | 200 | nC | 10 |
| Battery Current (OSC On) | I _{BAT1} | | | 350 | nA | 7 |
| Battery Current (OSC Off) | I _{BAT2} | | | 200 | nA | 7,21 |

DS2404

| CAPACITANCE | | | | | (t | $A = 25^{\circ}C$ |
|--------------------|---------------------|-----|-----|-----|-------|-------------------|
| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| Input Capacitance | C _{IN} | | | 10 | pF | |
| Output Capacitance | C _{OUT} | | | 15 | pF | |
| I/O (1-Wire) | I _{IN/OUT} | | 100 | 800 | pF | 8 |
| | | | | | | |

| RESISTANCES | | | | | (-40°C t | o +85°C) |
|--------------------------|------------------|-----|-----|-----|----------|----------|
| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| RST Resistance to Ground | Z _{RST} | | 65 | | kΩ | |
| DQ Resistance to Ground | Z _{DQ} | | 65 | | kΩ | |
| CLK Resistance to Ground | Z _{CLK} | | 65 | | kΩ | |

AC ELECTRICAL CHARACTERISTICS: 3-WIRE PORT

| 3-WIRE PORT | | | (-40°C | to +85°C | $V_{\rm CC} = 5$ | V+ 10%) |
|--------------------------------------|--------------------------------|-----|--------|----------|------------------|---------|
| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| Data to CLK Setup | t _{DC} | 35 | | | ns | 2 |
| CLK to Data Hold | t _{CDH} | 40 | | | ns | 2 |
| CLK to Data Delay | t _{CDD} | | | 100 | ns | 2,3,4 |
| CLK Low Time | $t_{\rm CL}$ | 250 | | | ns | 2 |
| CLK High Time | t _{CH} | 250 | | | ns | 2 |
| CLK Frequency | t _{CLK} | DC | | 2.0 | MHz | 2 |
| CLK Rise and Fall | t _R ,t _F | | | 500 | ns | 2 |
| RST to CLK Setup | t _{CC} | | | | μs | 2 |
| CLK to RST Hold | t _{CCH} | 40 | | | ns | 2 |
| RST Inactive Time | t _{CWH} | 250 | | | ns | 2 |
| CLK or \overline{RST} to DQ High Z | t _{CDZ} | | | 50 | ns | 2 |

AC ELECTRICAL CHARACTERISTICS:

 \bigcirc

| 1-WIRE PORT | | | (-40°C 1 | to +85°C; | $V_{CC}=2.8$ | to 5.5V) |
|----------------------|----------------------|-----|----------|-----------|--------------|----------|
| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | NOTES |
| Time Slot | t _{SLOT} | 60 | | 120 | μs | |
| Write 1 Low Time | t _{LOW1} | 1 | | 15 | μs | 23 |
| Write 0 Low Time | t _{LOW0} | 60 | | 120 | μs | |
| Read Low Time | t _{LOWR} | 1 | | 15 | μs | 23 |
| Read Data Valid | t _{RDV} | | 15 | | μs | 22 |
| Release Time | t _{RELEASE} | 0 | 15 | 45 | μs | |
| Read Data Setup | t_{SU} | | | 1 | μs | 15 |
| Recovery Time | t _{REC} | 1 | | | μs | |
| Interrupt | t _{INT} | 960 | | 4800 | μs | |
| Reset Time High | t _{RSTH} | 480 | | | μs | 14 |
| Reset Time Low | t _{RSTL} | 480 | | 960 | μs | 20 |
| Presence Detect High | t _{PDH} | 15 | | 60 | μs | |
| Presence Detect Low | t _{PDL} | 60 | | 240 | μs | |

NOTES:

- 1. All voltages are referenced to ground.
- 2. $V_{IH} = 2.0V$ or $V_{IL} = 0.8V$ with 10ns maximum rise and fall time.
- 3. $V_{DQH} = 2.4V$ and $V_{DQL} = 0.4V$, respectively.
- 4. Load capacitance = 50 pF.
- 5. Measured with outputs open.
- 6. When battery is applied to V_{BATO} input, V_{CC} and V_{BATB} must be 0V.
- 7. V_{BATB} , or $V_{BATO} = 3.0V$; all inputs inactive state.
- 8. Capacitance on the I/O pin could be 800pF when power is first applied. If a $5k\Omega$ resistor is used to pull-up the I/O line to V_{PUP}, 5µs after power has been applied, the parasite capacitance will not affect normal communications.
- 9. For auto-mode operation of the interval timer, the high level on the I/O pin must be greater than or equal to 70% of V_{CC} or V_{BATO} .
- 10. Read and write scratchpad (all 32 bytes) at 3.0V.
- 11. All other inputs at CMOS levels.
- 12. V_{PUP} = external pull-up voltage.
- 13. Input load is to ground.
- 14. An additional reset or communication sequence cannot begin until the reset high time has expired.
- 15. Read data setup time refers to the time the host must pull the I/O line low to read a bit. Data is guaranteed to be valid within 1μ s of this falling edge.
- 16. Under certain low voltage conditions V_{IL1MAX} may have to be reduced to as much as 0.5V to always guarantee a presence pulse.
- 17. Applies to 1 Hz and \overline{IRQ} pins only.
- 18. Applies to DQ pin only.
- 19. Applies to DQ, 1Hz and $\overline{\text{IRQ}}$ pins only.

- 20. The reset low time (t_{RSTL}) should be restricted to a maximum of 960µs, to allow interrupt signaling, otherwise, it could mask or conceal interrupt pulses.
- 21. When the battery is attached, the oscillator powers up in the off state.
- 22. The optimal sampling point for the master is as close as possible to the end time of the 15µs t_{RDV} period without exceeding t_{RDV} . For the case of a Read-one time slot, this maximizes the amount of time for the pull-up resistor to recover the line to a high level. For a Read-zero time slot it ensures that a read will occur before the fastest 1-Wire device(s) release the line ($t_{RELEASE} = 0$).
- 23. The duration of the low pulse sent by the master should be a minimum of 1µs with a minimum value as short as possible to allow time for the pull-up resistor to recover the line to a high level before the 1-Wire device samples in the case of a Write 1 Low Time or before the master samples in the case of a Read Low Time.

| | | | [| | | SITE | | PART N SEARC |
|---|---|-----------------------|---|--|---|---|--|--|
| | | | l | | | | | |
| HAT'S NEW PRODUC | TS SOLUTI | ONS | DESIGN | APPNOTES | SUPPORT | BUY | COMPANY | MEMBER |
| | | | _ | S2404 | | | | |
| Notes: | | | Part N | lumber Ta | ble | | | |
| Other options Didn't Find Whone business of Part number s data sheet or | at You Need day. uffixes: T or Part Naming | ? Ask our T&R = ta | applications | s engineers. Ex | kpert assista | nce in finding p | arts, usuall | |
| 5. * Some packa uses. | ges have var | | | drawing. "Pkg | JCode/Variat | ion" tells which | variation t | he product |
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| uses. | Free | Buy | Package: PDIP;16 pir Dwg: 56-G | TYPE PINS S DRAWING CO | DDE/VAR * | | RoHS/Le Materials | ad-Free? s Analysis d-Free: No |
| uses. | Free | Buy | PDIP;16 pir Dwg: 56-G Use pkgcod PDIP;16 pir Dwg: 56-G | TYPE PINS S DRAWING CO n;300 5005-002A (PE le/variation: P | DDE/VAR * DF) 16-4* DF) | Temp | RoHS/Le Materials RoHS/Lea Materials | ad-Free? s Analysis d-Free: No Analysis d-Free: Yes |
| uses. Part Number DS2404-001 | Free | Buy | Package: PDIP;16 pir Dwg: 56-G Use pkgcod PDIP;16 pir Dwg: 56-G Use pkgcod SOIC;16 pi Dwg: 56-G | TYPE PINS S DRAWING CO 5005-002A (PE le/variation: P n;300 5005-002A (PE le/variation: P | DIZE DDE/VAR * DF) 16-4* DF) 16+4* DF) | Temp OC to +70C | RoHS/Lea Materials RoHS/Lea Materials | ad-Free? s Analysis d-Free: No Analysis d-Free: Yes Analysis d-Free: Yes |
| uses. Part Number DS2404-001 DS2404-001+ | Free | Buy | PDIP;16 pir Dwg: 56-G Use pkgcod PDIP;16 pir Dwg: 56-G Use pkgcod SOIC;16 pi Dwg: 56-G Use pkgcod SOIC;16 pi Dwg: 56-G Use pkgcod | TYPE PINS S DRAWING CO 5005-002A (PE le/variation: P n;300 5005-002A (PE le/variation: P in;300 4009-001B (PE le/variation: W | DF) 16-4* DF) 16+4* DF) 16+4* DF) /16+3* DF) | Temp 0C to +70C -40C to +85C | RoHS/Lea Materials RoHS/Lea Materials RoHS/Lea Materials | ad-Free? s Analysis d-Free: No Analysis d-Free: Yes Analysis d-Free: Yes Analysis d-Free: No |
| uses. Part Number DS2404-001 DS2404-001+ DS2404S-001+T&R | Free | Buy | Package: PDIP;16 pir Dwg: 56-G Use pkgcod PDIP;16 pir Dwg: 56-G Use pkgcod SOIC;16 pi Dwg: 56-G Use pkgcod SOIC;16 pi Dwg: 56-G Use pkgcod SOIC;16 pi Dwg: 56-G Use pkgcod | TYPE PINS S DRAWING CO 5005-002A (PE le/variation: P n;300 5005-002A (PE le/variation: P in;300 4009-001B (PE le/variation: W in;300 4009-001B (PE le/variation: W | DF) 16-4* DF) 16+4* DF) 16+4* DF) /16+3* DF) /16-3* DF) | Temp 0C to +70C -40C to +85C 0C to +70C | RoHS/Lea Materials RoHS/Lea Materials RoHS/Lea Materials RoHS/Lea Materials | ad-Free? Analysis d-Free: No Analysis d-Free: Yes Analysis d-Free: Yes Analysis d-Free: No Analysis d-Free: No |

SSOP;16 pin;209 Dwg: 21-0056C (PDF) Use pkgcode/variation: A16-3*

DS2404B/T&R

RoHS/Lead-Free: No Materials Analysis

0C to +70C

| DS2404B | | SSOP;16 pin;209 Dwg: 21-0056C (PDF) Use pkgcode/variation: A16-3* | 0C to +70C | RoHS/Lead-Free: No Materials Analysis |
|-------------------------|-----|---|--------------|---|
| DS2404B+ | | SSOP;16 pin;209 Dwg: 21-0056C (PDF) Use pkgcode/variation: A16+3* | -40C to +85C | RoHS/Lead-Free: Yes Materials Analysis |
| DS2404B+T&R | | SSOP;16 pin;209 Dwg: 21-0056C (PDF) Use pkgcode/variation: A16+3* | -40C to +85C | RoHS/Lead-Free: Yes Materials Analysis |
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